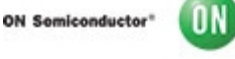

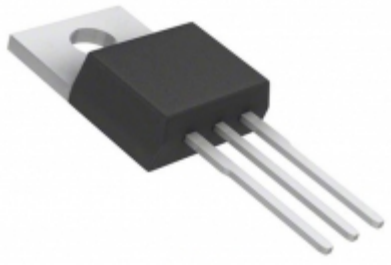




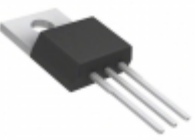
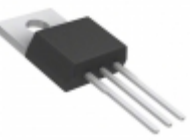



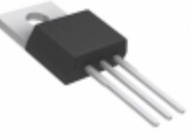
| | |
|--|---|
|   | <h2 style="color: red;">FDP15N50</h2> |
| | <p>Hersteller-Teilenummer: FDP15N50</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 500V 15A TO-220AB</p> <p>Datenblätter: 1.FDP15N50.pdf 2.FDP15N50.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 14999 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|--|---|
| Teilenummer | FDP15N50 |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | MOSFET N-CH 500V 15A TO-220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 14999 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 300W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 500V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 15A (Tc) |
| Rds On (Max) @ Id, Vgs | 380 mOhm @ 7.5A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 41nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1850pF @ 25V |
| Verpackung | Tube |

FDP15N50 ist neu im Original. Suche FDP15N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDP15N50 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FDP15N50: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|--|--|
|  <p>FDP15N40 Fairchild/ON Semiconductor MOSFET N-CH 400V 15A TO-220</p> |  <p>FDP15N50 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 15A TO-220AB</p> |  <p>FDP150N10A_F102 Fairchild/ON Semiconductor FDP150N10A_F102 Fairchild/ON Semiconductor</p> |  <p>FDP150N10A-F102 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 50A TO-220-3</p> |
|  <p>FDP15N65 AMI Semiconductor / ON Semiconductor MOSFET N-CH 650V 15A TO-220</p> |  <p>FDP16AN08A0 AMI Semiconductor / ON Semiconductor MOSFET N-CH 75V 58A TO-220AB</p> |  <p>FDP15N65 Fairchild/ON Semiconductor MOSFET N-CH 650V 15A TO-220</p> |  <p>FDP16AN08A0 Fairchild/ON Semiconductor MOSFET N-CH 75V 58A TO-220AB</p> |

heiße Teile

Mehr

| | | | | |
|--------------|-----------------|-------------|---------------|--------------|
| FDP120AN15A0 | FDP120AN15AO | FDP120N10 | FDP120N10 | FDP12N50 |
| FDP12N50 | FDP12N50NZ | FDP12N50NZ | FDP12N60NZ | FDP12N60NZ |
| FDP13AN06A0 | FDP13AN06A0 | FDP13AN06AO | FDP14AN06LA0 | FDP14AN06LA0 |
| FDP14AN06LA0 | FDP14N60 | FDP150N10 | FDP150N10 | FDP150N10A |
| FDP150N10A | FDP150N10A_F102 | FDP15N40 | FDP15N40 | FDP15N50 |
| FDP15N65 | FDP15N65 | FDP16AN08A0 | FDP16AN08A0 | FDP16AN08AO |
| FDP16AN098A0 | FDP16N50 | FDP16N50 | FDP16N50-0704 | FDP18N20F |
| FDP18N20F | FDP18N20V2 | FDP18N50 | FDP18N50 | FDP19N40 |
| FDP19N40 | FDP20AN06A0 | FDP20AN06AO | FDP20AN06AO | FDP20N50 |
| FDP20N50 | FDP20N50F | FDP20N50F | FDP20N60 | FDP22N50N |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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